

## Features

- High density cell design for ultra low  $R_{DS(on)}$
- Fully characterized avalanche voltage and current
- Excellent package for good heat dissipation

## Product Summary

| $V_{DS}$ | $R_{DS(ON)} \text{ MAX}$ | $I_D \text{ MAX}$ |
|----------|--------------------------|-------------------|
| -60V     | 35mΩ@-10V                | -10A              |
|          | 50mΩ@-4.5V               |                   |

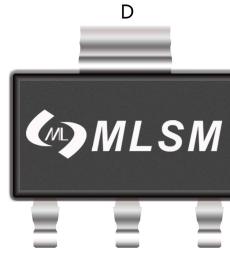
## Application

- PWM applications
- Power management
- Load switch

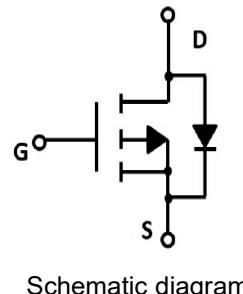


0G10AP: Device code  
XXXX: Code

Marking and pin assignment



SOT-223 top view



Schematic diagram



Halogen-Free

## Absolute Maximum Ratings (TA=25°C unless otherwise noted)

| Symbol | Parameter | Rating | Unit |
|--------|-----------|--------|------|
|--------|-----------|--------|------|

## Common Ratings (TC=25°C Unless Otherwise Noted)

|           |                                  |            |     |
|-----------|----------------------------------|------------|-----|
| $V_{DS}$  | Drain-Source Breakdown Voltage   | -60        | V   |
| $V_{GS}$  | Gate-Source Voltage              | $\pm 20$   | V   |
| $T_J$     | Maximum Junction Temperature     | 150        | °C  |
| $T_{STG}$ | Storage Temperature Range        | -55 to 150 | °C  |
| $I_S$     | Diode Continuous Forward Current | Tc=25°C    | -10 |
|           |                                  |            | A   |

## Mounted on Large Heat Sink

|           |  |         |     |      |
|-----------|--|---------|-----|------|
| $I_{DM}$  | Pulse Drain Current Tested             | Tc=25°C | -40 | A    |
| $I_D$     | Continuous Drain Current               | Tc=25°C | -40 | A    |
| $P_D$     | Maximum Power Dissipation              | Tc=25°C | 1.7 | W    |
| $R_{θJA}$ | Thermal Resistance Junction-to-Ambient |         | 315 | °C/W |

## Ordering Information (Example)

| Type     | Package | Marking | Minimum Package(pcs) | Inner Box Quantity(pcs) | Outer Carton Quantity(pcs) | Delivery Mode |
|----------|---------|---------|----------------------|-------------------------|----------------------------|---------------|
| MT0G10AP | SOT-223 | 0G10AP  | 2,500                | 5,000                   | 35,000                     | 13" reel      |

**Electrical Characteristics (T<sub>J</sub>=25°C unless otherwise noted)**

| Symbol  | Parameter                        | Condition   | Min  | Typ  | Max  | Unit |
|---|----------------------------------|---|------|------|------|------|
| <b>Static Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)</b> |                                  |   |      |      |      |      |
| BV <sub>(BR)DSS</sub>   | Drain-Source Breakdown Voltage   | V <sub>GS</sub> =0V, I <sub>D</sub> =-250μA               | -60  | -    | -    | V    |
| I <sub>DSS</sub>  | Zero Gate Voltage Drain Current  | V <sub>DS</sub> =-60V, V <sub>GS</sub> =0V                | --   | --   | -1   | μA   |
| I <sub>GSS</sub>  | Gate-Body Leakage Current        | V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V                | --   | --   | ±100 | nA   |
| V <sub>GS(th)</sub>   | Gate Threshold Voltage           | V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250μA | -1.0 | -1.8 | -2.5 | V    |
| R <sub>DS(on)</sub>   | Drain-Source On-State Resistance | V <sub>GS</sub> =-10V, I <sub>D</sub> =-10A               | --   | 25   | 35   | mΩ   |
|   |                                  | V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-5A               | --   | 38   | 50   | mΩ   |

**Dynamic Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)**

|                  |                              |  |    |      |    |    |
|------------------|------------------------------|--|----|------|----|----|
| C <sub>ISS</sub> | Input Capacitance            | V <sub>DS</sub> =-30V, V <sub>GS</sub> =0V, f=1MHz | -- | 3880 | -- | pF |
| C <sub>OSS</sub> | Output Capacitance           |  | -- | 169  | -- | pF |
| C <sub>RSS</sub> | Reverse Transfer Capacitance |  | -- | 138  | -- | pF |

**Switching Characteristics**

|                     |                     |  |    |      |    |    |
|---------------------|---------------------|--|----|------|----|----|
| Q <sub>g</sub>      | Total Gate Charge   | V <sub>DS</sub> =-30V, I <sub>D</sub> =-10A, V <sub>GS</sub> =-10V                     | -- | 111  | -- | nC |
| Q <sub>gs</sub>     | Gate Source Charge  |  | -- | 25   | -- | nC |
| Q <sub>gd</sub>     | Gate Drain Charge   |  | -- | 15.5 | -- | nC |
| t <sub>d(on)</sub>  | Turn-on Delay Time  |  | -- | 20   | -- | nS |
| t <sub>r</sub>      | Turn-on Rise Time   | V <sub>DD</sub> =-10V, I <sub>D</sub> =-10A, V <sub>GS</sub> =-10V, R <sub>G</sub> =6Ω | -- | 25   | -- | nS |
| t <sub>d(off)</sub> | Turn-Off Delay Time |  | -- | 71   | -- | nS |
| t <sub>f</sub>      | Turn-Off Fall Time  |  | -- | 30   | -- | nS |

**Source-Drain Diode Characteristics**

|                 |                    |  |    |    |      |   |
|-----------------|--------------------|--|----|----|------|---|
| V <sub>SD</sub> | Forward on voltage | T <sub>j</sub> =25°C, I <sub>s</sub> =-10A | -- | -- | -1.2 | V |
|-----------------|--------------------|--|----|----|------|---|

### Typical Operating Characteristics

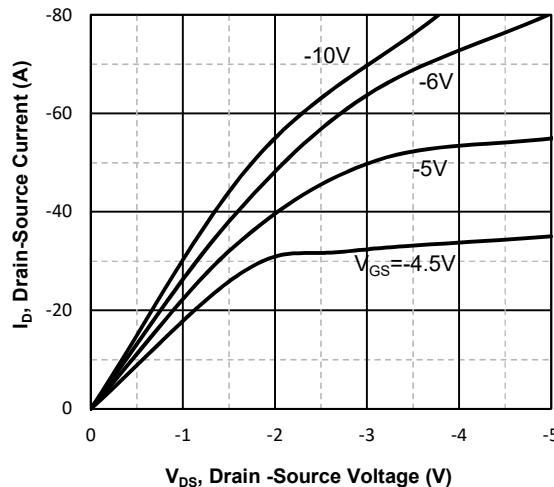


Fig1. Typical Output Characteristics

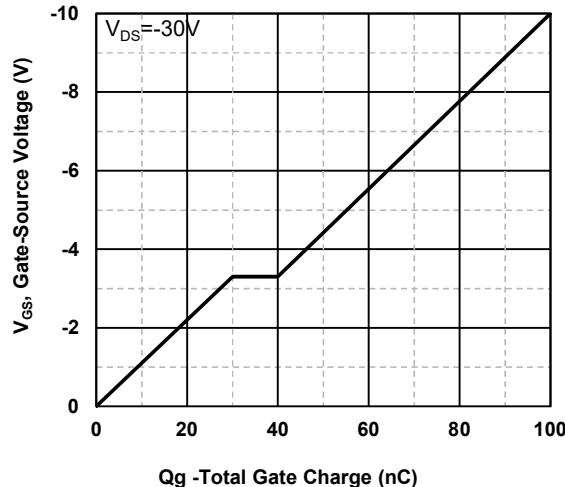


Fig2. Typical Gate Charge Vs.Gate-Source Voltage

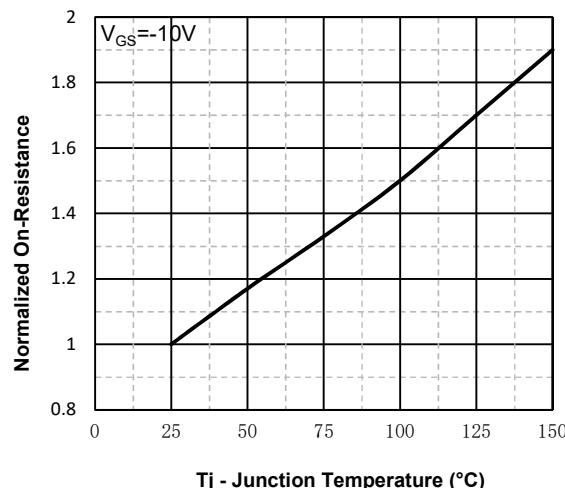


Fig3. Normalized On-Resistance Vs. Temperature

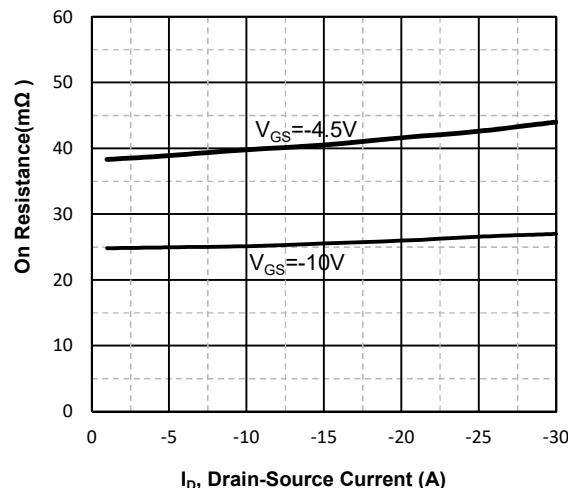


Fig4. Drain-Source on Resistance Vs.Drain-Source Current

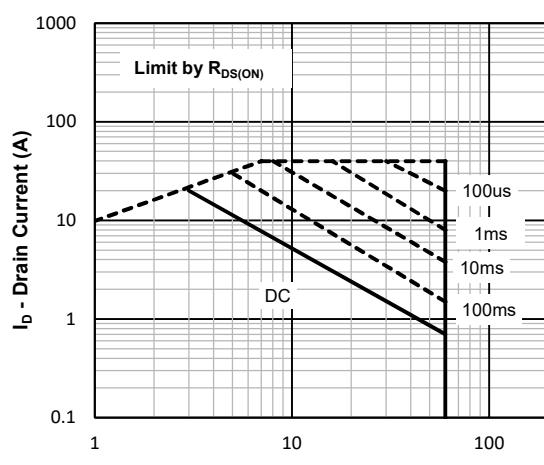


Fig5. Maximum Safe Operating Area

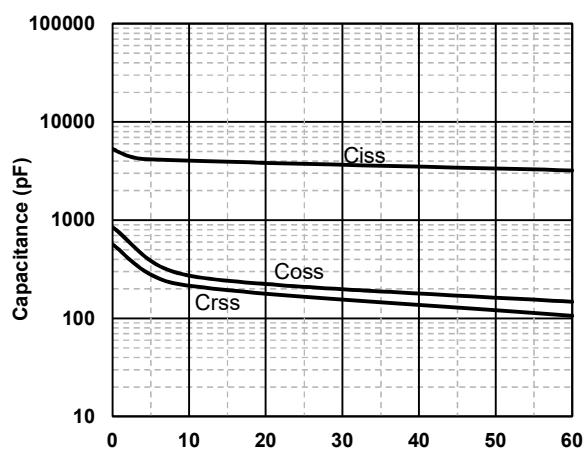
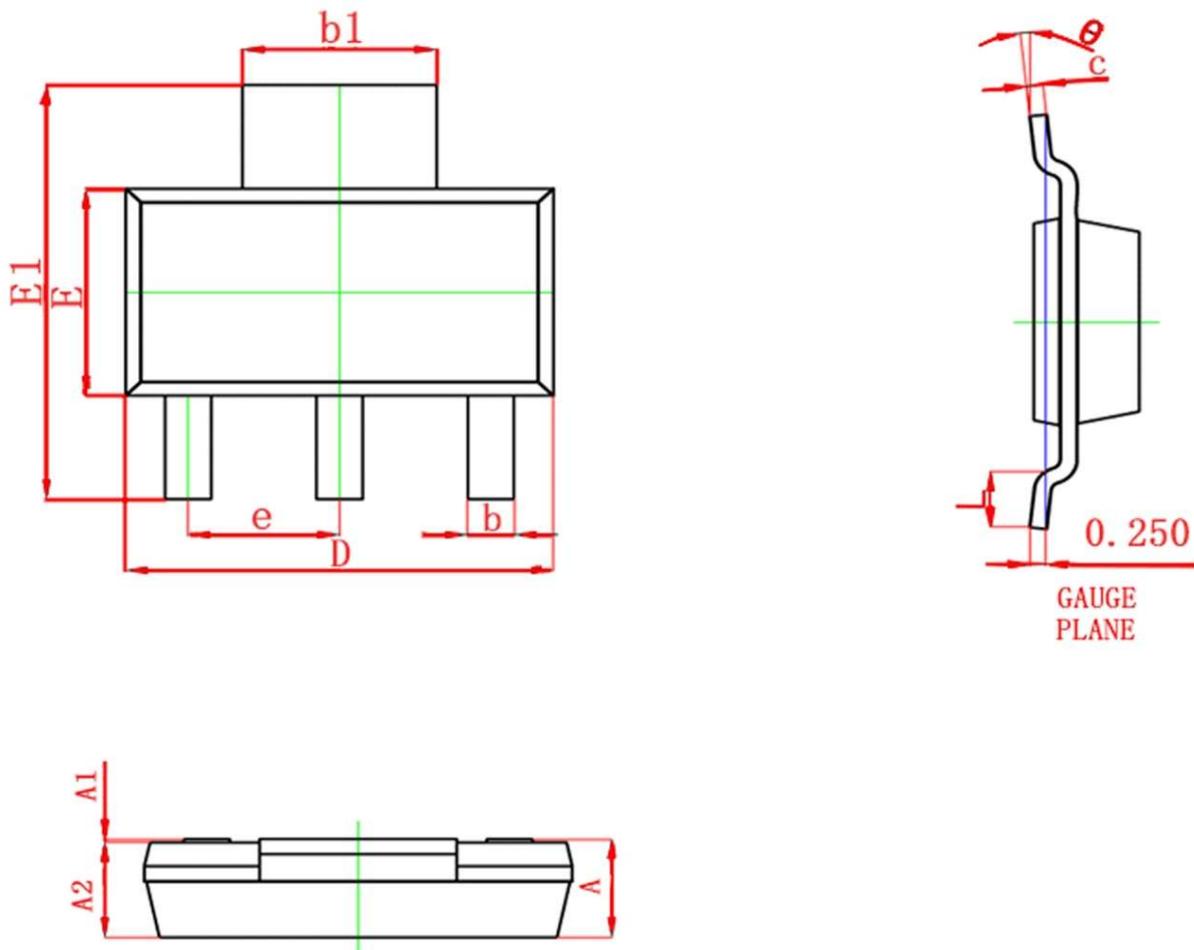


Fig6. Typical Capacitance Vs.Drain-Source Voltage

## SOT-223 Package information



| Symbol    | Dimensions in Millimeters(mm) |       | Dimensions In Inches |       |
|-----------|-------------------------------|-------|----------------------|-------|
|           | Min                           | Max   | Min                  | Max   |
| <b>A</b>  | --                            | 1.800 | --                   | 0.071 |
| <b>A1</b> | 0.020                         | 0.100 | 0.001                | 0.004 |
| <b>A2</b> | 1.500                         | 1.700 | 0.059                | 0.067 |
| <b>b</b>  | 0.660                         | 0.840 | 0.026                | 0.033 |
| <b>b1</b> | 2.900                         | 3.100 | 0.114                | 0.122 |
| <b>c</b>  | 0.230                         | 0.350 | 0.009                | 0.014 |
| <b>D</b>  | 6.300                         | 6.700 | 0.248                | 0.264 |
| <b>E</b>  | 3.300                         | 3.700 | 0.130                | 0.146 |
| <b>E1</b> | 6.700                         | 7.300 | 0.264                | 0.287 |
| <b>e</b>  | 2.300(BSC)                    |       | 0.091(BSC)           |       |
| <b>L</b>  | 0.750                         | --    | 0.030                | --    |
| <b>θ</b>  | 0°                            | 10°   | 0°                   | 10°   |